



DMN601TK

#### N-CHANNEL ENHANCEMENT MODE FIELD-EFFECT TRANSISTOR

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
001/	2Ω @ V <sub>GS</sub> = 10V	0.3A
60V	3Ω @ V <sub>GS</sub> = 5V	0.2A

#### **Description and Applications**

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) yet maintain superior switching performance, making it ideal for highefficiency power-management applications.

- Motor controls
- Power-management functions

### **Features and Benefits**

- Low On-Resistance: RDS(ON)
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- ESD Protected Up to 2kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.

https://www.diodes.com/quality/product-definitions/

An automotive-compliant part is available under separate datasheet (DMN601TKQ)

#### **Mechanical Data**

- Package: SOT523
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Ansnealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Terminal Connections: See Diagram
- Weight: 0.002 grams (Approximate)

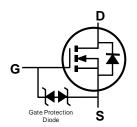
SOT523



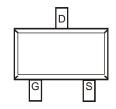
ESD Protected up to 2kV



Top View



**Equivalent Circuit** 



Top View Pin Out Configuration

April 2024

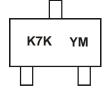
# Ordering Information (Note 4)

Part Number	Dookono	Packing			
Part Number	Package	Qty.	Carrier		
DMN601TK-7	SOT523	3000	Tape & Reel		

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + CI) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



K7K = Product Type Marking Code YM = Date Code Marking Y or  $\overline{Y}$  = Year (ex: L = 2024) M = Month (ex: 4 = April)

Data Codo Koy

Year	2005	-	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033
Code	S	-	L	М	N	Р	R	S	T	U	V	W
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec



# **Maximum Ratings** (@ $T_A = +25$ °C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		VDSS	60	V
Gate-Source Voltage		$V_{GSS}$	±20	V
Drain Current (Note 5)	Continuous Pulsed (Note 6)	lo	300 800	mA

## Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient	Reja	833	°C/W
Operating and Storage Temperature Range	TJ, TSTG	-65 to +150	°C

## **Electrical Characteristics** (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0$ , $I_D = 10\mu A$
Zero Gate Voltage Drain Current	IDSS		_	1.0	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0
Gate-Source Leakage	Igss	_	_	±10	μΑ	$V_{GS} = \pm 20V$ , $V_{DS} = 0$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	1.0	1.6	2.5	V	$V_{DS} = 10V$ , $I_D = 1mA$
Static Drain-Source On-Resistance	D-s(s)		1.3	2.0	Ω	$V_{GS} = 10V, I_D = 0.5A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	_	1.4	3.0	12	$V_{GS} = 5V, I_D = 0.05A$
Forward Transfer Admittance	Y <sub>F</sub> S	80	_	_	ms	$V_{DS} = 10V, I_{D} = 0.2A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss			50	рF	V 05V V 0
Output Capacitance	Coss	_	_	25	pF	$V_{DS} = 25V, V_{GS} = 0,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	_	_	5.0	pF	11 = 1.0lvin2
Turn-On Delay Time	td(ON)	_	3.4	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	2.4	_	ns	$V_{DD} = 25V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)	_	11.0	_	ns	$R_G = 25\Omega$ , $I_D = 500mA$
Turn-Off Fall Time	t <sub>F</sub>		4.9	_	ns	

Notes:

- 5. Device mounted on FR-4 PCB.
- 6. Pulse width  $\leq 10 \mu s, \ Duty \ Cycle \leq 1\%.$
- 7. Short duration pulse test used to minimize self-heating effect.
- 8. Guaranteed by design. Not subject to product testing.





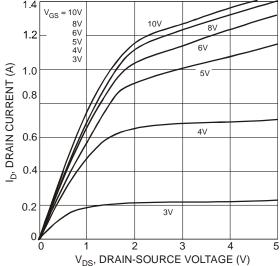
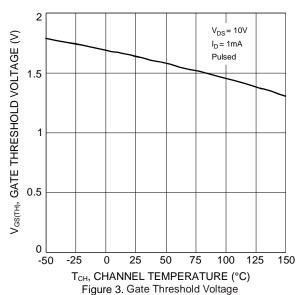


Figure 1. Typical Output Characteristics



vs. Channel Temperature

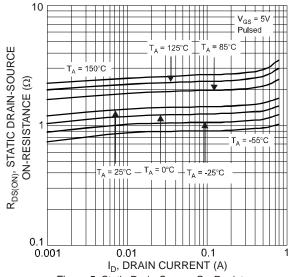
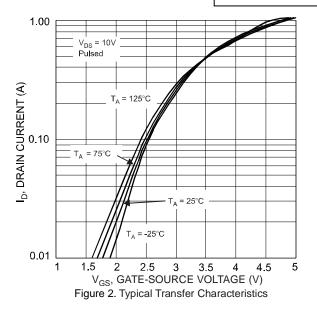
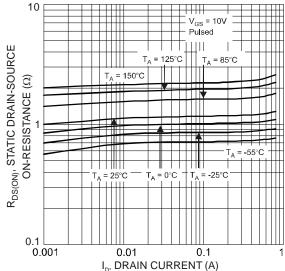
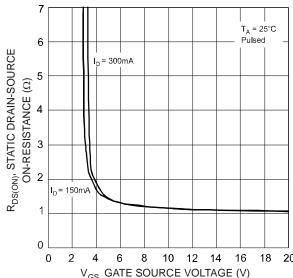


Figure 5. Static Drain-Source On-Resistance vs. Drain Current





I<sub>D</sub>, DRAIN CURRENT (A)
Figure 4. Static Drain-Source On-Resistance
vs. Drain Current



V<sub>GS,</sub> GATE SOURCE VOLTAGE (V) Figure 6. Static Drain-Source On-Resistance vs. Gate-Source Voltage



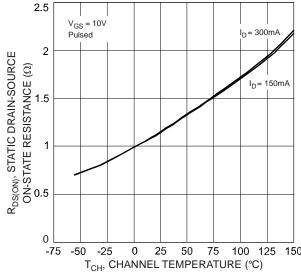
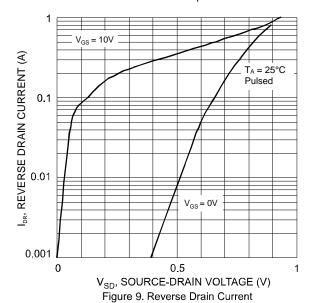
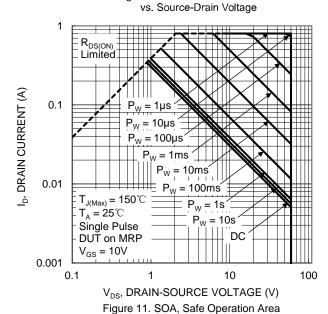
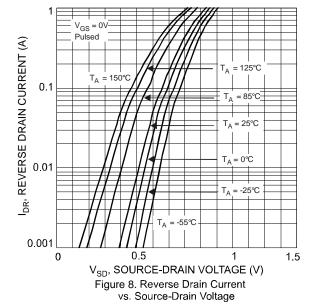


Figure 7. Static Drain-Source On-State Resistance vs. Channel Temperature







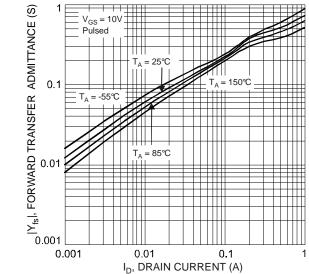


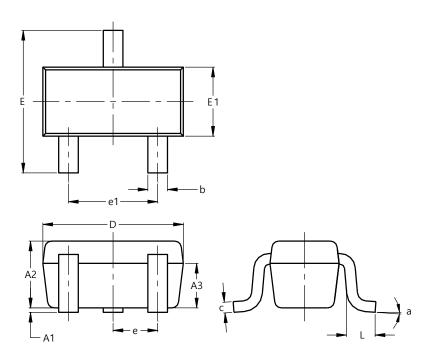
Figure 10. Forward Transfer Admittance vs. Drain Current



## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT523**

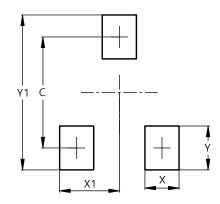


SOT523						
Dim	Min	Max	Тур			
A1	0.00	0.10	0.05			
A2	0.60	0.80	0.75			
А3	0.45	0.65	0.50			
b	0.15	0.30	0.22			
С	0.10	0.20	0.12			
D	1.50	1.70	1.60			
Е	1.45	1.75	1.60			
E1	0.75	0.85	0.80			
е	0.50 BSC					
e1	0.90	1.10	1.00			
L	0.20	0.40	0.33			
а	0°		8°			
All Dimensions in mm						

## **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### **SOT523**



Dimensions	Value (in mm)				
С	1.29				
Χ	0.40				
X1	0.70				
Υ	0.51				
Y1	1.80				



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